

ST2111FX

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

Features

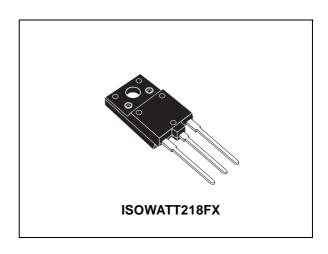
- NEW SERIES, ENHANCED PERFORMANCE
- FULLY INSULATED PACKAGE (U.L. COMPLIANT) FOR EASY MOUNTING
- HIGH VOLTAGE CAPABILITY (1500V)
- HIGH SWITCHING SPEED
- TIGTHER h_{fe} CONTROL
- IMPROVED RUGGEDNESS

Applications

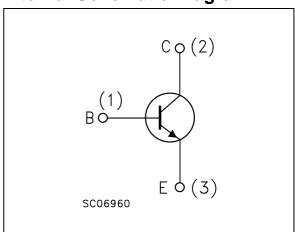
■ HORIZONTAL DEFLECTION AND SWITCH MODE POWER SUPPLY FOR TVs.

Description

The device is manufactured using Diffused Collector Technology for more stable operation vs base drive circuit variations resulting in very low worst case dissipation.



Internal Schematic Diagram



Order codes

Part Number	Marking	Package	Packing
ST2111FX	2111FX	ISOWATT218FX	TUBE

1 Electrical Ratings ST2111FX

1 Electrical Ratings

Table 1. Absolute Maximum Rating

Symbol	Parameter	Value	Unit
V _{CES}	Collector-Base Voltage (v _{BE} = 0)	1500	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)	700	V
V _{EBO}	Collector-Base Voltage (I _C = 0)	7	V
I _C	Collector Current	12	Α
I _{CM}	Collector Peak Current (t _P < 5ms)	25	Α
I _B	Base Current	7	Α
P _{TOT}	Total dissipation at T _c = 25°C	65	W
V _{isol}	Insulation Withstand Voltage (RMS) from All Three Leads to External Heatsink	2500	V
T _{STG}	Storage Temperature	-65 to 150	°C
T _J	Max. Operating Junction Temperature	150	°C

Table 2. Thermal Data

Symbol	Parameter	Value	Unit
R _{thJ-case}	Thermal Resistance Junction-Case Max	1.9	°C/W

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ST2111FX 2 Electrical Characteristics

2 Electrical Characteristics

Table 3. Electrical Characteristics ($T_{CASE} = 25^{\circ}C$; unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector Cut-off Current	V _{CE} = 1500V			1 2	mA mA
	$(V_{BE} = 0)$	V _{CE} = 1500V, Tj=125°C				ША
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 7V			1	mA
V _{CE(sus)} Note: 1	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 100mA	700			V
V _{CE(sat)} Note: 1	Collector-Emitter Saturation Voltage	$I_C = 8 A$ $I_B = 2 A$			3	V
V _{BE(sat)} Note: 1	Base-Emitter Saturation Voltage	$I_C = 8 \text{ A}$ $I_B = 2 \text{ A}$			1.5	V
h _{FE}		$I_C = 1 A$ $V_{CE} = 5 V$		25		
Note: 1	DC Current Gain	$I_C = 8 A$ $V_{CE} = 5 V$	4.5		9	
	INDUCTIVE LOAD	I _C =6 A f _h =64KHz				
t _s	Storage Time	$I_{B(on)}$ =1 A $V_{BE(off)}$ =-2.5 \	/	2.3	3	μs
t _f	Fall Time	L _{BB(off)} =1.3µH		0.16	0.35	μs

Note: 1 Pulsed duration = 300 μ s, duty cycle \leq 1.5%.

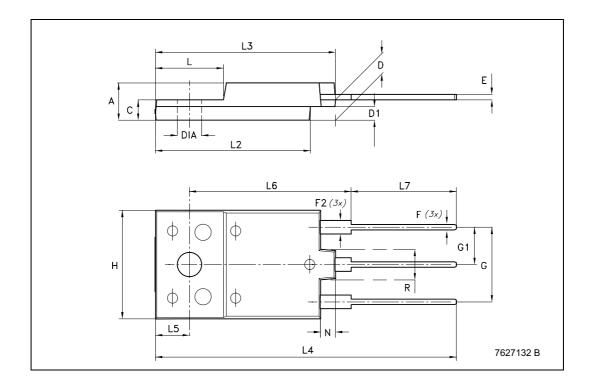


3 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

ISOWATT218FX MECHANICAL DATA

DIM.		mm.			
	MIN.	TYP	MAX.		
Α	5.30		5.70		
С	2.80		3.20		
D	3.10		3.50		
D1	1.80		2.20		
E	0.80		1.10		
F	0.65		0.95		
F2	1.80		2.20		
G	10.30		11.50		
G1		5.45			
Н	15.30		15.70		
L	9		10.20		
L2	22.80		23.20		
L3	26.30		26.70		
L4	43.20		44.40		
L5	4.30		4.70		
L6	24.30		24.70		
L7	14.60		15		
N	1.80		2.20		
R	3.80		4.20		
Dia	3.40		3.80		



4 Revision History ST2111FX

4 Revision History

Date	Revision	Changes
18-Oct-2005	1	First Issue

ST2111FX 4 Revision History

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